

### Low Capacitance TVS Diode Array

### **■**FEATURES

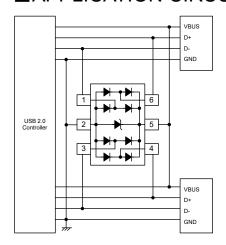
Terminal Capacitance : 1.0pF (Line-to-GND)
ESD Protection : 8kV Contact (IEC61000-4-2)

 $\textbf{Environmentally Friendly} \qquad : \mathsf{EU} \ \mathsf{RoHS} \ \mathsf{Compliant}, \ \mathsf{Pb} \ \mathsf{Free}$ 

### APPLICATIONS

- ●USB2.0, Firewire
- ●Video Graphics Card
- DVI
- Ethernet 10/100/1000

### ■APPLICATION CIRCUIT



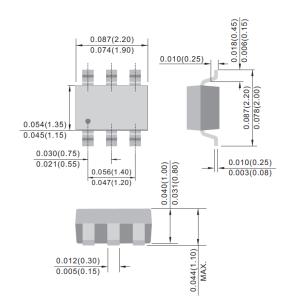
### **■**PRODUCT NAME

PRODUCT NAME	PACKAGE	ORDER UNIT
XBP1002-G *	SOT-363	3,000 / Reel

<sup>\*</sup> The "-G" suffix denotes Halogen and Antimony free as well as being fully RoHS compliant.

### ■ PACKAGING INFORMATION

●SOT-363 Unit: inch (mm)



### ■ ABSOLUTE MAXIMUM RATINGS

Ta=25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Peak Pulse Power (8/20 µs Waveform)	Ppk	150	W
Peak Pulse Current (8/20 & Waveform)	lpp	6	А
Junction Temperature	Tj	-55 to 150	°C
Storage Temperature	Tstg	-55 to 150	°C



### **■**ELECTRICAL CHARACTERISTICS

Ta=25°C

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			LINUTO
			MIN.	TYP.	MAX.	UNITS
Stand-Off Voltage	V <sub>RWM</sub>		-	-	5	V
Breakdown Voltage	$V_{BR}$	I <sub>R</sub> =1mA, Pin5 to 2	6	-	-	V
Leakage Current	I <sub>R</sub>	V <sub>R</sub> =5V, Pin5 to 2	ı	1	3	μA
Clamping Voltage (8/20 µs)	Vc	I <sub>PP</sub> =1A, I/O pin to Pin2	-	-	15	V
Clamping Voltage (8/20 µs)	Vc	I <sub>PP</sub> =6A, I/O pin to Pin2	-	-	25	V
Terminal Capacitance	Ct	V <sub>R</sub> =0V, f=1MHz Between I/O lines and GND	-	-	1	pF
		V <sub>R</sub> =0V, f=1MHz Between I/O lines	-	-	0.5	pF

### **■**NOTES ON USE

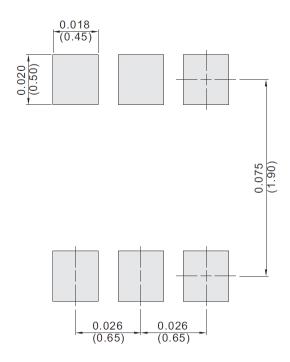
- 1. Please use this IC within the absolute maximum ratings.

  Even within the ratings, in case of high load use continuously such as high temperature, high voltage, high current and thermal stress may cause reliability degradation of the IC.
- 2. Torex places an importance on improving our products and their reliability.

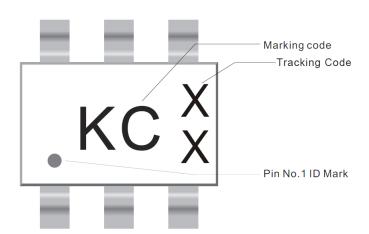
  We request that users incorporate fail-safe designs and post-aging protection treatment when using Torex products in their systems.

# ■REFERENCE PATTERN LAYOUT

●SOT-363

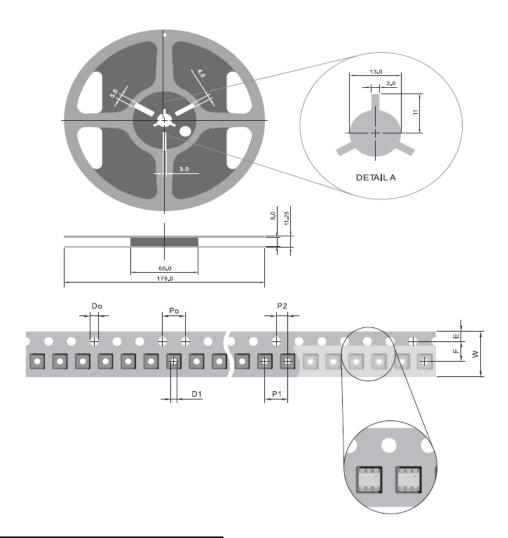


## **■**MARKING



# ■ TAPING SPECIFICATIONS

### ●SOT-363



D0 1.50 $\pm$ 0.10 D1 1.00 $\pm$ 0.25 E 1.75 $\pm$ 0.10 F 3.50 $\pm$ 0.05	SYMBOL	mm
D1 $1.00 \pm 0.25$ E $1.75 \pm 0.10$		
E 1.75 ± 0.10	טט	1.50 ± 0.10
	D1	1.00 ± 0.25
F 3.50 ± 0.05	E	1.75 ± 0.10
	F	$3.50 \pm 0.05$
P0 4.00 ± 0.10	P0	4.00 ± 0.10
P1 4.00 ± 0.10	P1	4.00 ± 0.10
P2 2.00 ± 0.05	P2	2.00 ± 0.05
W 8.00 + 0.3 -0.1	W	8.00

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